

	Type	L #	Hits	Search Text	DBs
1	BRS	L4	9357	dielectric near2 temperature	US- PGPUB; USPAT; EPO; JPO; DERWEN T; IBM_TD B
2	BRS	L5	151	(microelectromechanical or micro-electromechanical or micro-electro-mechanical or mems or microactuator) and 4	US- PGPUB; USPAT; EPO; JPO; DERWEN T; IBM_TD B
3	BRS	L6	84258	dielectric same temperature	US- PGPUB; USPAT; EPO; JPO; DERWEN T; IBM_TD B
4	BRS	L7.	682	(microelectromechanical or micro-electromechanical or micro-electro-mechanical or mems or microactuator) same 6	US- PGPUB; USPAT; EPO; JPO; DERWEN T; IBM_TD B

	Type	L #	Hits	Search Text	DBs
5	BRS	L8	48373	dielectric with temperature	US- PGPUB; USPAT; EPO; JPO; DERWEN T; IBM_TD B
6	BRS	L9	130	(microelectromechanical or micro-electromechanical or micro-electro-mechanical or mems or microactuator) same 8	US- PGPUB; USPAT; EPO; JPO; DERWEN T; IBM_TD B
7	BRS	L10	262087 6	conduct\$3	US- PGPUB; USPAT; EPO; JPO; DERWEN T; IBM_TD B
8	BRS	L11	170867	sacrific\$4	US- PGPUB; USPAT; EPO; JPO; DERWEN T; IBM_TD B

	Type	L #	Hits	Search Text	DBs
9	BRS	L12	79	10 same 11 same 8	US- PGPUB; USPAT; EPO; JPO; DERWEN T; IBM_TD B
10	BRS	L13	15	(microelectromechanical or micro-electromechanical or micro-electro-mechanical or mems or microactuator) and 12	US- PGPUB; USPAT; EPO; JPO; DERWEN T; IBM_TD B
11	BRS	L14	755	form same dielectric same ("200" "300") same degrees	US- PGPUB; USPAT; EPO; JPO; DERWEN T; IBM_TD B
12	BRS	L15	59527	(microelectromechanical or micro-electromechanical or micro-electro-mechanical or mems or microactuator)	US- PGPUB; USPAT; EPO; JPO; DERWEN T; IBM_TD B

	Type	L #	Hits	Search Text	DBs
13	BRS	L16	92	L14 and L15	US- PGPUB; USPAT; EPO; JPO; DERWEN T; IBM_TD B
14	BRS	L17	16630	silicon adj oxynitride	US- PGPUB; USPAT; EPO; JPO; DERWEN T; IBM_TD B
15	BRS	L18	323	(silane sih4 ("SiH.sub.4")) with ("nitrous oxide" n2o("N.sub.2O")) with (nitrogen n2 ("N.sub.2")) with (NH3 ("NH.sub.3"))	US- PGPUB; USPAT; USOCR
16	BRS	L20	20422	pecvd ("plasma enhanced chemcial vapor deposition")	US- PGPUB; USPAT; EPO; JPO; DERWEN T; IBM_TD B
17	BRS	L21	31038	Sion (silicon adj oxynitride)	US- PGPUB; USPAT; EPO; JPO; DERWEN T; IBM_TD B

	Type	L #	Hits	Search Text	DBs
18	BRS	L22	6422	L21 with dielectric	US- PGPUB; USPAT; EPO; JPO; DERWEN T; IBM_TD B
19	BRS	L24	1005	335/78.ccls. 200/181.ccls.	US- PGPUB; USPAT; EPO; JPO; DERWEN T; IBM_TD B
20	BRS	L19	174	L17 and L18	US- PGPUB; USPAT; USOCR
21	BRS	L23	262	L22 with L20	US- PGPUB; USPAT; EPO; JPO; DERWEN T; IBM_TD B